



4.0A GLASS PASSIVATED BRIDGE RECTIFIER

Product Summary (@TA = +25°C)

V _{RRM} (V)	I _O MAX (A)	V _F MAX (V)	I _R MAX (μA)
400, 600, 800, 1000	4	1.1	5

Features and Benefits

- Glass Passivated Die Construction
- Rating to 1000V PRV
- Low Reverse Leakage Current
- Surge Overload Rating to 130A Peak
- Ideal for Printed Circuit Board Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)

Description and Applications

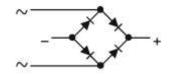
Suitable for AC to DC bridge full wave rectification for AC/DC Power Supply, LED lighting, home appliances, office equipment, and telecommunication applications.

Mechanical Data

- Case: KBP
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Tin. Plated Leads, Solderable per MIL-STD-202, Method 208
- Polarity: Marked on Body
- Weight: 1.52 grams (Approximate)

KBP





Equivalent Circuit

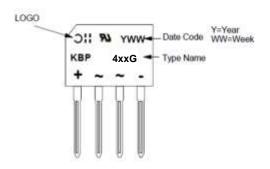
Ordering Information (Note 3)

Part Number	Compliance	Case	Packaging
KBP404G	Commercial	KBP	35 Pieces per Tube
KBP406G	Commercial	KBP	35 Pieces per Tube
KBP408G	Commercial	KBP	35 Pieces per Tube
KBP410G	Commercial	KBP	35 Pieces per Tube

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristic	Symbol	KBP404G	KBP406G	KBP408G	KBP410G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	400	600	800	1000	V
RMS Reverse Voltage	V _{R(RMS)}	280	420	560	700	V
Average Rectified Output Current @T _C = +105°C (With Heatsink) (Without Heatsink)	lo			.0 .0		Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}		10	30		Α
Non-Repetitive Peak Forward Surge Current 1.0ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}		26	60		Α
I^2t Rating for Fusing (3ms $\leq t \leq 8.3$ ms)	l ² t		5	0		A^2s

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Case (Note 4)	$R_{ heta JC}$	6	°C/W
Typical Thermal Resistance, Junction to Lead (Note 4)	$R_{ heta JL}$	8	°C/W
Typical Thermal Resistance, Junction to Ambient (Note 4)	$R_{ heta JA}$	15	°C/W
Typical Thermal Resistance, Junction to Case (Note 5)	$R_{ heta JC}$	14	°C/W
Typical Thermal Resistance, Junction to Lead (Note 5)	$R_{ heta JL}$	20	°C/W
Typical Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	40	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min		Min		Min		Тур	Max	Unit	Test Condition
	1,000 KBP410G										
Reverse Breakdown Voltage		800	KBP408G			V	1 5				
(Note 6)	$V_{(BR)R}$	600	KBP406G	T —	_		$I_R = 5\mu A$				
	400 KBP404G										
Forward Voltage Drop per Element	V _F	_		0.94	1.1	V	I _F = 4.0A, T _J = +25°C				
Leakage Current (Note 6)	IR	_		_	5 500	μA	V _R = 1000V, T _J = +25°C V _R = 1000V, T _J = +125°C				
Total Capacitance per Element	Ст	_		40	_	pF	$V_R = 4.0V_{DC}$, $f = 1MHz$				

Notes: 4. Thermal resistance per element. Device mounted on 75mm x 75mm x 1.6mm Cu Plate Heatsink.

6. Short duration pulse test used to minimize self-heating effect.

^{5.} Thermal resistance per element without heatsink.



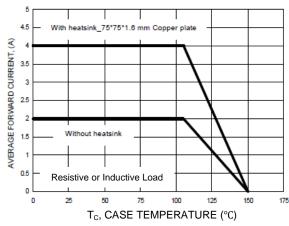


Figure 1. Forward Current Derating Curve

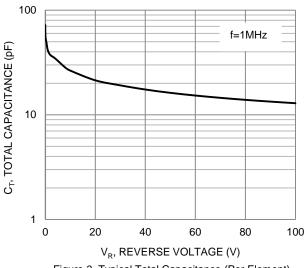
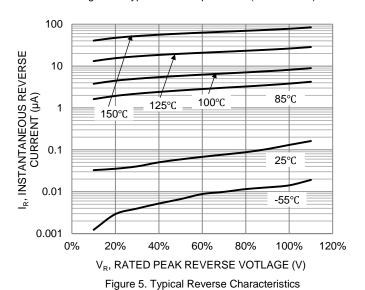


Figure 3. Typical Total Capacitance (Per Element)



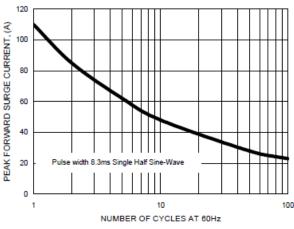


Figure 2. Maximum Non-repetitive Surge Current

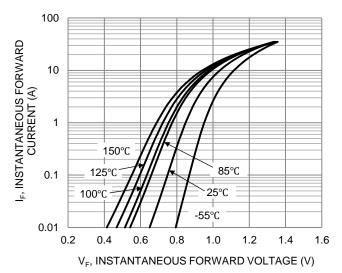


Figure 4. Typical Forward Characteristics

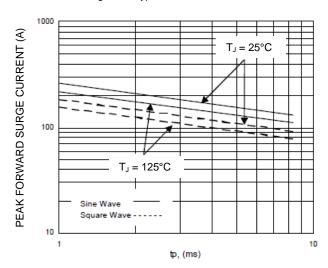


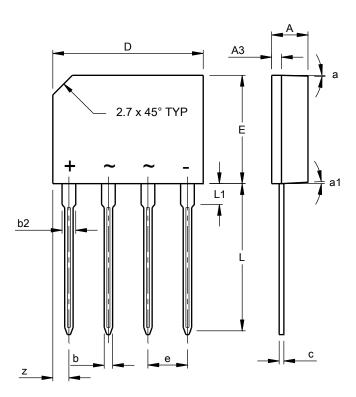
Figure 6. Non-repetitive Surge Current



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

KBP



КВР						
Dim	Min	Тур				
Α	3.35	3.65	-			
A3	0.80	1.10	-			
b	0.76	0.86	-			
b2	1.22	1.42	-			
С	0.35	0.55	-			
D	14.25	14.75	-			
Е	10.20	10.60	-			
е	3.56	4.06	-			
L	14.25	14.73	-			
L1	1.80	2.20	-			
Z	1.40	1.70	-			
а	-	-	3°			
a1	-	-	2°			
All Dimensions in mm						



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